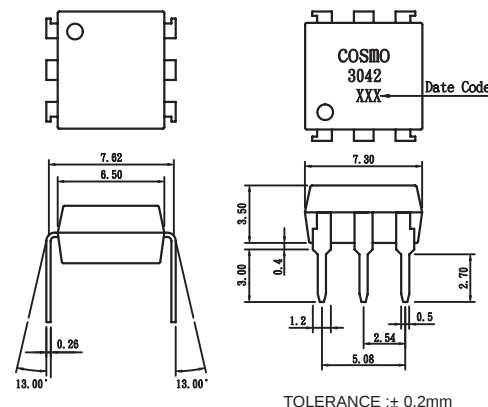


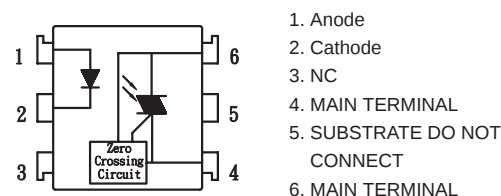
For 115/240 Vac (rms) Application:

1. Solenoid/Valve Controls.
2. Lighting Controls.
3. Static Power Switches.
4. AC Motor Drives.
5. Temperature Controls.
6. E. M. Contactors.
7. AC Motor Staters.
8. Solid State Relays.

Outside Dimension:Unit (mm)



Schematic:Top View



Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	IF	50	mA
	Peak forward current	IFM	1	A
	Reverse voltage	VR	6	V
	Power dissipation	PD	70	mW
Output	Off-State Output Terminal voltage	VDRM	400	Vpeak
	Peak Repetitive Surget Current	ITSM	6	A
	Power dissipation	PD	300	mW
Total power dissipation		Ptot	330	mW
Isolation voltage 1 minute		Viso	5000	Vrms
Operating temperature		Topr	-40 to +80	°C
Storage temperature		Tstg	-40 to +125	°C
Soldering temperature 10 seconds		Tsol	260	°C

Electro-optical Characteristics

(Ta=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	VF	IF=10mA		1.2	1.5	V
	Reverse Leakage Current	IR	VR=4V			10	μA
Output	Peak Blocking Current	IDRM	VDRM=Rated		60	500	nA
	ON-State Voltage	VTM	ITM=100mA		1.8	3	V
	Critical rate of rise of OFF-state voltage	dV/dt		600			V/μS
Transfer characteristics	Holding Current	IH			100		μA
	Inhibit Voltage (MT1-MT2 Voltage above which device not trigger.)	VINH	IF=10mA		5	20	V
	Leakage in Inhibited State	IDRM2	IF=Rated IF, Rated VDRM, Off State			500	μA
	Isolation resistance	Riso	DC500V	5x10 ¹⁰	10 ¹¹		ohm
	Minimum trigger current	IFT	Main Terminal Voltage=3V			10	mA

Fig.1 On-State Characteristics

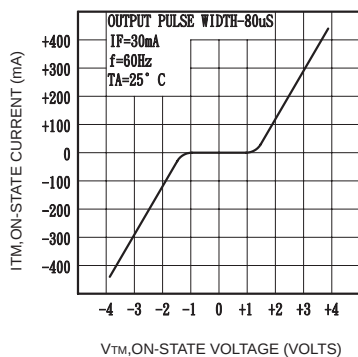


Fig.2 Inhibit Voltage versus Temperature

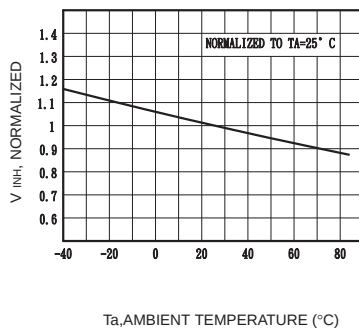


Fig.3 Leakage with LED Off versus Temperature

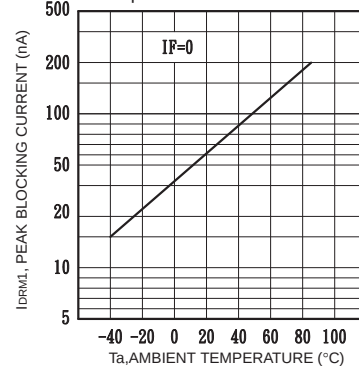


Fig.4 IDRM2, Leakage in Inhibit State versus Temperature

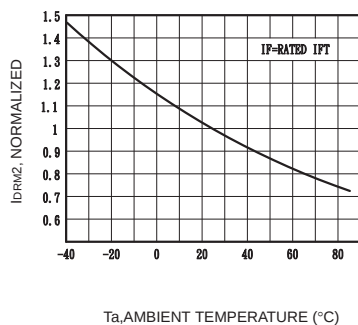


Fig.5 Trigger Current versus Temperature

